

TOSHIBA RF POWER AMPLIFIER MODULE

S-AU27AL, S-AU27AM, S-AU27AH

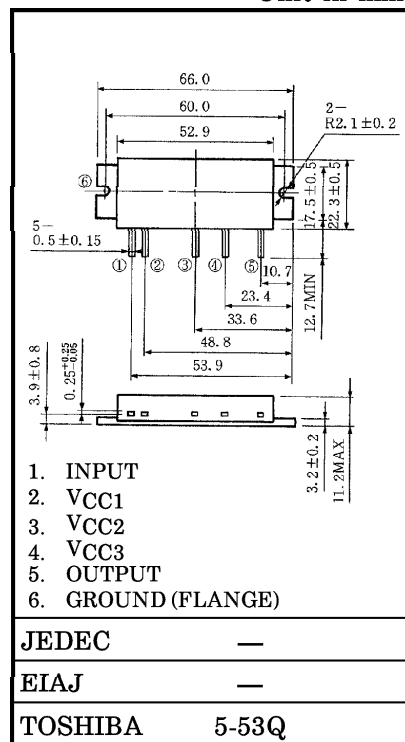
25W FM RF POWER AMPLIFIER MODULE

Unit in mm

- S-AU27AL : f=400~430MHz
- S-AU27AM : f=450~490MHz
- S-AU27AH : f=490~512MHz

MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	VCC1	16	V
DC Supply Voltage	VCC2	17	V
DC Supply Voltage	VCC3	17	V
Total current	IT	10	A
Input Power	Pi	600	mW
Output Power	Po	40	W
Operating Case Temperature Range	Tc(opr)	-30~100	°C
Storage Temperature Range	Tstg	-40~110	°C



ELECTRICAL CHARACTERISTICS (Tc = 25°C)

Weight : 35g

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Frequency Range	f _{range}	—	400	—	512	MHz
Output Power	Po	VCC1 = VCC2 = VCC3 = 12.5V Pi = 200mW ZG = ZL = 50Ω	32	—	—	W
Power Gain	Gp		22.0	—	—	dB
Total Efficiency	η _T		35	—	—	%
Input VSWR	VSWR _{in}		—	1.5	2.5	—
Harmonics	HRM		—	-30	-25	dB
Load Mismatch	—	Po = 35W (VCC1 = adjust) VCC2 = VCC3 = 15V Pi = 200mW VSWR load 20 : 1 all phase	No Degradation			—
Stability	—	VCC2 = VCC3 = 12.5V VCC1 = 3~12.5V Pi = 200mW VSWR load 3 : 1 all phase	All spurious output than 60dB below desired signal			—

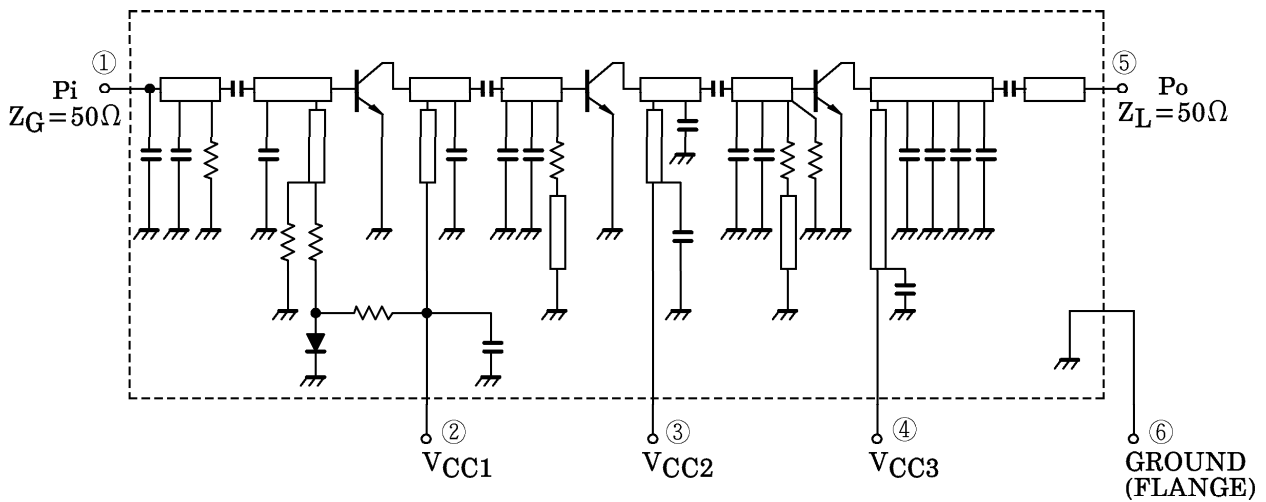
CAUTION

- This product has intersetting cap. Please pay attention for exceeding stress and foreign matter in your application. And not to take away the cap.
- Beryllia Ceramics is used in this product. The dust or vapor can be dangerous to humans. Do not break, cut, crush or dissolve chemically. Dispose of this product properly according to law. Do not intermingle with normal industrial or domestic waste.

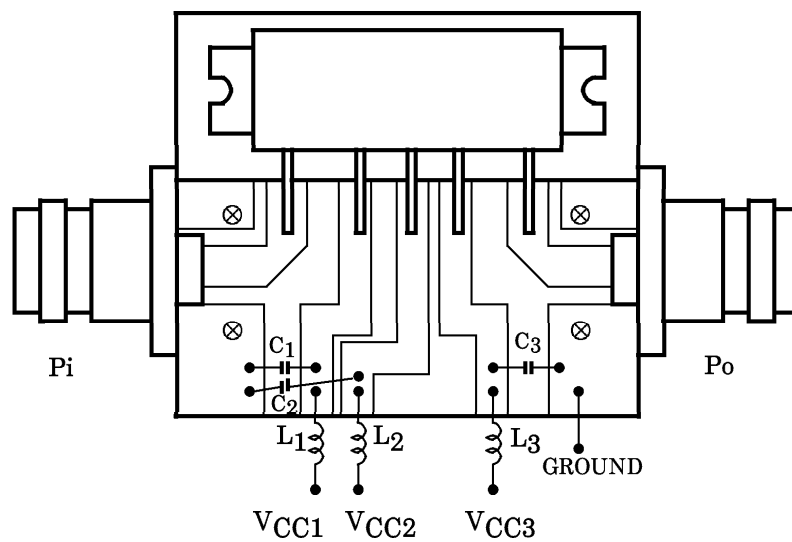
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● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

SCHEMATIC



TEST FIXTURE

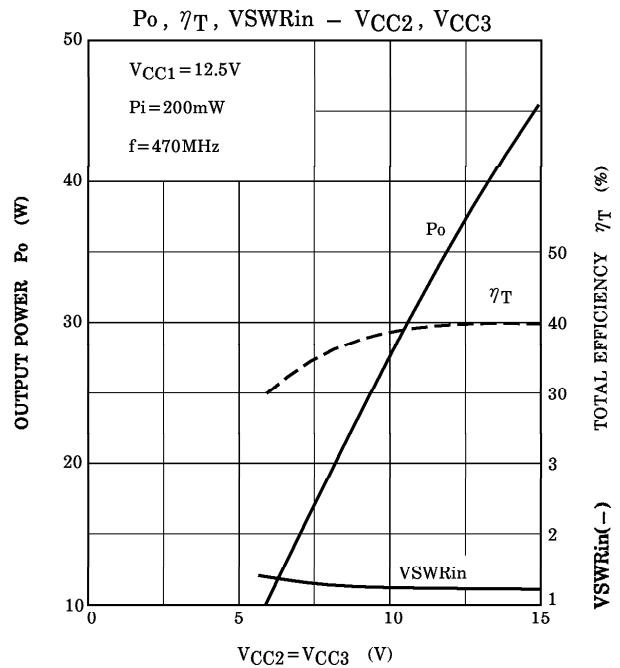
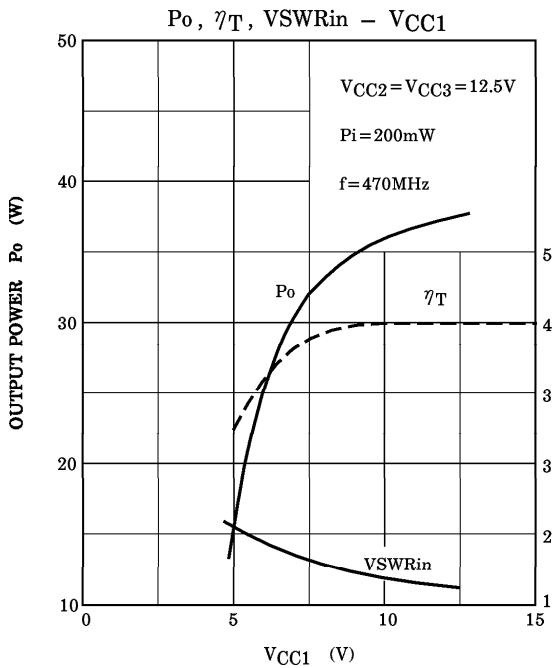
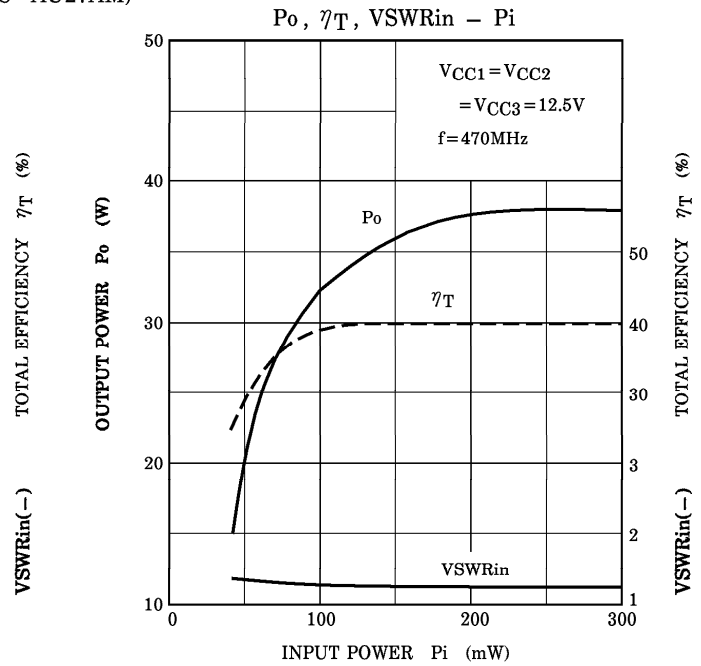
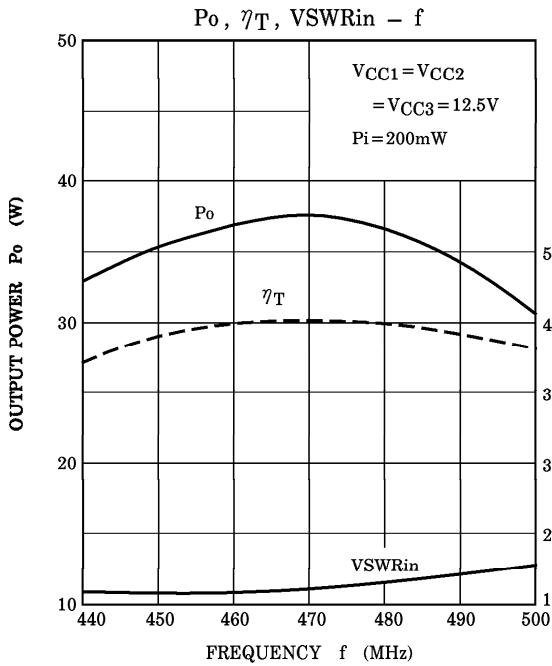


C : 15000pF, 10 μ F PARALLEL
 L : ϕ 0.8 ENAMEL WIRE 8T, 5ID

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**TYPICAL PERFORMANCE CURVE
(S-AU27AM)**



CAUTION

These are only typical curves and devices are not necessarily guaranteed at these curves.